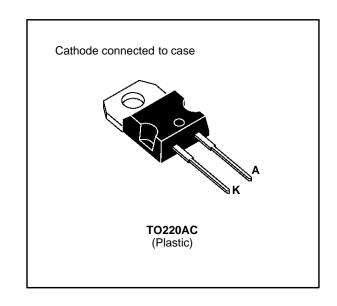


# **BYT 08P-1000**

# FAST RECOVERY RECTIFIER DIODE

- VERY HIGH REVERSE VOLTAGE CAPABILITY
- VERY LOW REVERSES RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING



#### **SUITABLE APPLICATIONS**

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

### **ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	1000	V	
V <sub>RSM</sub>	Non Repetitive Peak Reverse Voltage		1000	V
I <sub>FRM</sub>	Repetitive Peak Forward Current	t <sub>p</sub> ≤ 10μs	100	А
I <sub>F (RMS)</sub>	RMS Forward Current	16	Α	
I <sub>F (AV)</sub>	Average Forward Current	$T_c = 115^{\circ}C$ $\delta = 0.5$	8	А
I <sub>FSM</sub>	Surge Non Repetitive Forward Current	t <sub>p</sub> = 10ms Sinusoidal	50	А
Р	Power Dissipation	T <sub>c</sub> = 115°C	17	W
T <sub>stg</sub> T <sub>j</sub>	Storage and Junction Temperature Range	- 40 to + 150 - 40 to + 150	°C	

#### THERMAL RESISTANCE

ſ	Symbol	Parameter	Value	Unit
	R <sub>th (j - c)</sub>	Junction-case	2	°C/W

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## **ELECTRICAL CHARACTERISTICS**

## STATIC CHARACTERISTICS

Synbol	Test Conditions			Тур.	Max.	Unit
I <sub>R</sub>	T <sub>j</sub> = 25°C	$V_R = V_{RRM}$			35	μΑ
	T <sub>j</sub> = 100°C				2	mA
V <sub>F</sub>	T <sub>j</sub> = 25°C	I <sub>F</sub> = 8A			1.9	V
	T <sub>j</sub> = 100°C				1.8	

## RECOVERY CHARACTERISTICS

Symbol	Test Conditions				Min.	Тур.	Max.	Unit
t <sub>rr</sub>	T <sub>j</sub> = 25°C	I <sub>F</sub> = 1A	$di_F/dt = -15A/\mu s$	$V_R = 30V$			155	ns
		I <sub>F</sub> = 0.5A	I <sub>R</sub> = 1A	$I_{rr} = 0.25A$			65	

# TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions			Тур.	Max.	Unit
t <sub>IRM</sub>	di <sub>F</sub> /dt = - 32A/μs	V <sub>CC</sub> = 200 V I <sub>F</sub> = 8A			200	ns
	di <sub>F</sub> /dt = - 64A/μs	$L_p \le 0.05 \mu H$ $T_j = 100^{\circ}C$ See Figure 1		120		
I <sub>RM</sub>	di <sub>F</sub> /dt = - 32A/μs				5.5	Α
	di <sub>F</sub> /dt = - 64A/μs			6		

# TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

Symbol	Test Condition s				Тур.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	$T_j = 100^{\circ}C$ $d_{iF}/dt = -8A/\mu s$	$V_{CC} = 200V$ $L_p = 12\mu H$	$I_F = I_{F (AV)}$ See figure 2			4.5	

To evaluate the conduction losses use the following equations:

$$V_F = 1.47 + 0.041 I_F$$
  $P = 1.47 \times I_{F(AV)} + 0.041 I_{F^2(RMS)}$ 

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Figure 1. Turn-off switching characteristics (without series inductance).

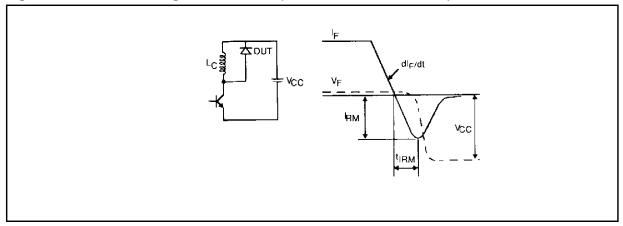
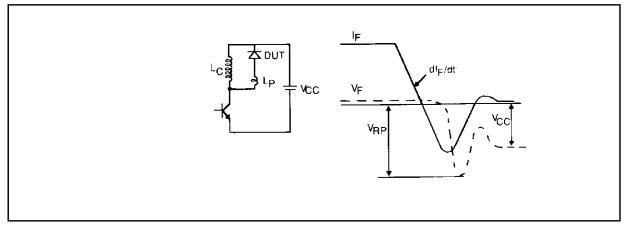
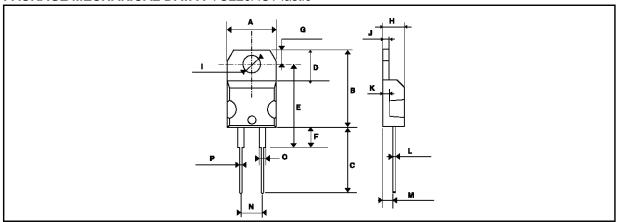


Figure 2. Turn-off switching characteristics (with series inductance).



#### PACKAGE MECHANICAL DATA: TO220AC Plastic



	DIMENSIONS					
REF.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
Α	10.0	10.4	0.393	0.409		
В	15.2	15.9	0.598	0.626		
С	13	14	0.511	0.551		
D	6.2	6.6••••	0.244	0.260		
E	16.4 typ.		0.645 typ.			
F	3.5	4.2	0.137	0.165		
G	2.65	2.95	0.104	0.116		
Н	4.4	4.6	0.173	0.181		
I	3.75	3.85	0.147	0.151		
J	1.23	1.32	0.048	0.051		
K	1.27 typ.		0.050 typ.			
L	0.49	0.70	0.019	0.027		
М	2.4	2.72	0.094	0.107		
N	4.95	5.15	0.194	0.203		
0	1.14	1.70	0.044	0.067		
Р	0.61	0.88	0.024	0.034		

Cooling method: by conduction (method C) Marking: type number Weight: 2.42g

Recommended torque value: 80cm. N Maximum torque value: 100cm. N

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